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1	Strong etching formulation (time and rate) for PADC with deep depth bulk
2	etch rate study
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18 Abstract

Aqueous NaOH with ethanol (strong) etchant is widely used. It shortens 19 etching time effectively compared to normal etching conditions (6.25N NaOH at 20 70 °C). Two equations have been proposed to calculate the etching time with 21 NaOH molarity and ethanol volume. Another two empirical equations were 22 introduced for estimating the bulk etch rates of PADC etched in strong etchant. Up 23 to now, there were no such equations available in the literature that can predict 24 etching time and V_b of PADC with etchant molarity and ethanol volumes. The 25 proposed equations were compared to fundamental V_b models stemming from 26 literature. Fast etching enables the follow-up of bulk etch rate variation versus 27 depth in the detector material up to $\approx 80 \ \mu m$. In agreement with previous studies, 28 an equation is given which allows such variations to be expressed under the form 29 of a reciprocal bulk etch rate normalized to depth (i.e., removed layer). 30

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³³ Keywords:

<sup>PADC; Soft/strong etching; Arrhenius model; Multi-hit model; Bulk etch rate;
Etching time.</sup>

1. Introduction

The standard procedure when using solid-state nuclear track detectors (SSNTD) 39 is to reveal latent ion tracks by operating a chemical etching which makes them 40 visible under the optical or atomic force microscope. Commonly used etching 41 solutions in the literature are alkaline etchant such as NaOH or KOH with 42 concentration range of 6-7 N at temperatures of 60-70 °C [1-10]. However, a new 43 etchant solution composed of NaOH with different amounts of alcohols (ethanol 44 and/or methanol) has been used as a strong and active etchant [11-13]. Such 45 mixtures are very effective in reducing the time needed to reveal and measure 46 diameters of alpha tracks. Strong etching was found to provide a quadratic function 47 of growing alpha particle tracks diameter with etching time. So, the strong etching 48 can reduce the etching time by factor "4", and thus enhance the etching time [13]. 49 Processing many detectors can be time-consuming using normal etching compared 50 to strong one. Therefore, it requires fine-tuned analyses for better understanding 51 and use in routine work. 52

Poly-allyl-diclycol-carbonate (PADC) is mainly made of the monomer allyldiclycol-carbonate (ADC). ADC chemical structure contains two carbonate groups and one ether function. Its alkaline dissolution results in the loss of the carbonate groups from the residual molecule (see next section). This process is activated in the presence of hydroxyl ions available in an alkali solution (alkaline hydrolysis). The reaction is endothermic i.e., the process needs energy to be initiated and its rate increases with increasing temperature of the solution. In principle, two models were used to describe chemical etching process. The first one is Arrhenius model, accounting thermodynamic equilibrium of chemical reaction between educts and products in homogeneous phase. In this statistical consideration, the bulk etch rate can be determined as a function of etchant concentration (C), temperature (T), as follows [14]:

$$V_b(C,T,B,n,\varepsilon) = BC^n e^{\frac{c}{\kappa T}}$$
(1)

_ c

66 Where, *B* is the normalization constant, the power *n* (not necessary integer) 67 indicates the chemical reaction order and the activation energy ε (eV) are the 68 adjustable parameters. *k* is Boltzmann's constant. Its results are widely used as 69 well as accepted [15,16]. From this model, only two important parameters are 70 deduced: the order of chemical etching (n) and the activation energy of etching (ε).

The second is Multi-hit model (MHM, also known as v-hit) [17], in which the dissolution of the bulk material described by the number of hits (v) between the molecules of etchant and detector. The model is thus combining hits frequency with thermodynamic equations for a simultaneous interpretation of chemical reactions and diffusion processes. The basic idea of this model is to claim that the processes are initiated by single or repeated interactions or hits of the target (molecules, molecular fragments, emulsion grains and/or living cells). SSNTDs are
then considered as composed of sensitive nanometric volumes *(SNV)* and such *SNV*can switch from the state "*No*" to the etched state "*Yes*" after etching process with
a certain probability. Poisson's distribution describes this probability as below:

$$P_{\nu}(\xi) = 1 - \sum_{k=1}^{\nu-1} \frac{\xi^k}{k!} e^{-\xi}$$
(2)

These centres are etched if they suffer a fluctuating number of hits, v at the 82 nanometre scale by etchant molecules greater than some threshold value of v. 83 Parameter (ξ) represents the average number of hits per sensitive volume. Several 84 functions for bulk etch rate proposed in terms of multi-hit approximation [17]. In 85 the present study, the focus was on the effect of etchant concentration on etching 86 rate. Therefore, two modules were considered (where the concentration effect is 87 dominant) to calculate the detector bulk etch rate. Module 8 of multi-hit, we will 88 call it MHM-M8, in which $\xi = \frac{c}{c_0}$ and module 15 in which $\xi = \frac{c}{c_0} e^{\frac{\varepsilon}{kT}}$, we will call 89 it MHM-M15. More information about this model can be found in [18-22] and 90 references therein. MHM-M8 bulk etch rate can be written as: 91

92
$$V_b(C,T,B,\nu,\varepsilon,c_0) = BCe^{\frac{-\varepsilon}{KT}}P_{\nu}\left(\frac{C}{C_0}\right)$$

93 (3)

94 While bulk etch rate with MHM-M15 is as follows:

95

96
$$V_b(C,T,B,\nu,\varepsilon,c_0) = BCe^{\frac{-\varepsilon}{kT}}P_{\nu}\left(\frac{C}{C_0}e^{\frac{\varepsilon}{kT}}\right)$$

97

(4)

Many physical parameters can be deduced from this model, n, ε and number of hits necessary to activate the reaction between etchant molecules and detector molecules (v). Etching process is envisioned as a macroscopic process when described by those two models; however, much information about etching processes at the microscopic scale were ignored (see etching mechanism section).

103 Many empirical equations have been used to calculate bulk etch rates as 104 function of both C and T [23], such as for example:

105
$$V_b(a_1|a_5) = a_1 10^{(a_2C + a_3T - a_4CT - a_5)}$$

106 (5)

107 Where a_1 to a_5 are free adjusting parameters.

Recently, another equation assigned in terms of the etchant concentration (C), and free adjusting (a) and (b). This equation (referred here as Al-Jubbori-2016) was proposed in [5] as follows:

111
$$V_b = a(e^{bC} - 1)$$
 (6)

112 Nevertheless, since the involvement of the strong etching (NaOH plus ethanol)113 in 2005 [11] no equation was found to predict such specific bulk etch rates as a

function of the etchant concentration C at different ethanol fractions. Thus, the aim 114 of the present work is to introduce a new empirical equation that can predict the 115 etching time and the bulk etch rate in a wide NaOH concentration range (2-22N) of 116 different ethanol volume of 0, 1, 2 and 3 mL (corresponding to 0, 11, 20 and 27%) 117 volume fraction) that was added to 8 mL of aqueous NaOH solutions. 118 Additionally, an explanation to the rigorous bulk etch rate mechanism and the 119 significant reduce in etching time by strong etching is proposed. Strong etching is 120 used to investigate the bulk etch rate to deeper depth layers up to 80 µm or more. 121 Besides, a reciprocal bulk etch rate equation is going to be deduced and compared 122 with those of literature data. 123

124

2. Etching Mechanism

Since its discovery in 1978 [24], PADC (also known as CR-39TM) is considered 125 as one of the most successful SSNTD for detection of charged particles with linear 126 energy transfer greater than 10 keV/µm (in water) [25]. It is a highly cross-linked 127 thermoset polymer. Soft (NaOH/H₂O) and strong (NaOH/ethanol) etching 128 processes follow the same etching mechanism as illustrated in Figures 1-3. Etching 129 takes place due to scission of the carbonate ester bond by hydroxide ions through 130 basic hydrolysis of ester moiety (see Fig. 1). Electron rich hydroxide ions cause the 131 scission of ester linkage because carbonyl groups (C=O) are electrically polarized 132

(the carbon atom site is electron deficient). Electron transfer occurs thus from 133 electron rich region to electron deficient region, so that, OH groups will attack 134 electron deficient ones (carbonyl group) as shown in Fig. 2. In PADC there are 135 four possible positions which are subjected to cleavage by the hydroxide ion [26] 136 as shown in Fig. 3. Etching of PADC in NaOH/ethanol will fierce bulk etch rate of 137 the detector compared to NaOH/water. This may likely be due to the better 138 reactivity during etching and presumably to a better solubilization of organic etch-139 products released from PADC. Relative static permittivity (which provides a 140 measure of polarity) of pure methanol or ethanol are respectively 33 and 24 at 141 25°C, with quasi-identical dipolar moments of ≈ 1.70 debye (D); as water has a 142 relative static permittivity of typically 75 at 25°C (64 at 70°C) and a slightly higher 143 dipolar moment of ≈ 1.85 D [27]. A decrease of the dielectric constant (i.e., of the 144 relative static permittivity) of a given medium has a direct consequence on both 145 reactivity and miscibility. In media containing methanol or ethanol, the dielectric 146 constant is small, therefore attraction forces between electrical charges are 147 enhanced in comparison to pure water. It is therefore likely that addition of 148 alcohols in NaOH aqueous solution may partly lower the relative static permittivity 149 value of the etchant and thus it can enhance hydroxide ion reactivity on polar 150 groups (carbonate ester groups). 151

Fig. 3 shows that etch-products are mainly: saturated, unsaturated alcohols and 152 carbonate ions, the latter being strongly miscible in water. The basic solubility rule 153 states that "like dissolves like" but when applied to alcohols things become a bit 154 more complex. Alcohols are sparingly soluble in water; their solubilities decrease 155 with carbon chain length. Higher alcohols are insoluble in water. Organic alcohols 156 consist of a carbon chain (always non-polar) and a OH group (which is polar). It is 157 well-known for example that after 7th carbon atoms in a chain (i.e. for homologues 158 longer or equal to heptanol), alcohols are considered immiscible in pure water. By 159 mixing water and ethanol (or methanol), solubilities of both higher alcohols and 160 aromatic hydrocarbons (non-polar in nature) increase in water/ethanol mixtures as 161 the volume fraction of ethanol increases [27]. PADC etched products are thus more 162 soluble in ethanol than in water. The decrease in etching time is therefore likely to 163 be due to both of an enhancement of reactivity of the etchant (hydroxyl ions) and 164 an increase in solubility of organic etch products resulting in an increase in the 165 bulk etch rate, V_b. 166

167

168 **3. Experiment**

PADC detector sheet of thickness 650 μ m, manufactured by American Acrylics (US), was used. Detector sheet aging more than 20 years old was cut to small pieces of area 1 cm². Each piece was irradiated to fission fragments of ²⁵²Cf

for 30 min. Aqueous solution of 8 ml fresh NaOH with concentrations 2, 4, 6.25, 8, 172 10, 12, 14, 16, 18, 20, 22, 25, 27 and 30N were prepared, and different ethanol 173 volumes of 0, 1, 2 and 3 ml (equivalent to 0, 11, 20 and 27 % volume fractions) 174 were added to the NaOH solutions. The suggested equations (9 and 10) have tested 175 in both a limited NaOH concentration range (2-10N) where most applications are 176 carried out and in an extended NaOH concentration (2-22N) to show the capability 177 of the proposed equation. The etchant was kept at 70 °C by a water bath to avoid 178 ethanol evaporation noting that pure ethanol boils and evaporates at 78 °C and in a 179 mixture of water and NaOH at 95 °C. For more details about the experiment, please 180 refer to Awad et al., [8]. Etching time was varied for different etching conditions 181 to keep the removed bulk etch layer for each case close to $\approx 10 \ \mu m$. It was done due 182 to the limited range (~20-25 µm) of fission fragments in PADC detectors. After 183 etching of exposed detectors, diameters of fission fragment tracks were manually 184 measured using an optical microscope (OPTIKA B-1000BF-ALC, Italy). 185 Measurement resolution of track diameters was \pm 0.5 µm. The etching time 186 necessary to obtain fission track diameter $\approx 18 \ \mu m$ was determined at the different 187 etching conditions. Largest diameter of 40 almost circular fission fragment tracks, 188 D_{ff} were manually selected as much as possible and drawn as a function of the 189 etching time, t_e to determine the bulk etch rate [28] if the linear dependence of D_{ff} 190 (t_e) is applicable for all etching conditions [29]. 191

SSNTDs were irradiated to normal incident high energy ions of 7 GeV Si at 192 Bevelac, Berkeley, USA with particles density $\approx 1000-2000$ particles/cm². The 193 detectors were cut perpendicularly to the detector surface into several pieces of 194 area 1 cm². Each piece was etched in strong etching solution (8 mL of 18 N 195 NaOH+1mL ethanol) at 70°C for different successive etching times. Removed 196 layer, h was determined experimentally by measuring the change in detector 197 thicknesses using the optical microscope after the detector was mounted in its 198 edge. After etching, track cones shaped etch-pits were found by careful polishing 199 of the detector edge to produce ion's nuclear track profile for Si ions. The growth 200 of the cone shaped etch-pits for Si tracks at one side of the detector were followed 201 at different etching times. From the track cone length (L) at every etching step and 202 the corresponding removed layer, the track etch rate V_t was determined directly 203 [30-32]. For normally incident particle, the track etch rate at given removed layer, 204 h can be deduced if the track etching started immediately at the detector surface 205 without delay. Thus, the time dependent track length is available by track profile 206 technique and track etch rate is given as: 207

$$V_t(h) = \frac{dL(h)}{dt} + V_b \tag{7}$$

Aging effect for PADC detectors was previously studied for samples stored for 8 and 12 years [33]. Polymer degradation for PADC detectors was investigated microscopically using FTIR for new, medium age, and old detectors. It was proved that aging effect is not dominant and has minor effect on PADC specially for bulk and low γ -ray doses samples. Bulk etch rate of PADC (type PM-355) was found almost constant even after storage for a long time (about ten years) in air at room temperature in the absence of light in another study [34]. However, for a sample of age more than 12 years, the forecasted loss of sensitivity is about 2% per year.

217

4. Data analysis

4.1 Data fitting method

The non-linear fitting procedure was carried out by minimizing the χ^2 220 distribution iteratively for all the considered equations. Iteration process is repeated 221 many times using many seed numbers for the adjusted parameters till the lowest γ^2 222 is achieved [8]. Try and error method was used to obtain the global minimization 223 as much as possible. χ^2 values depend on degree of freedom, DF, which refers to 224 the maximum number of the logically independent values that have the freedom to 225 vary in the data sample (equals the number of the experimental data points minus 226 1). In the present work, the significant levels α was taken as 0.05. The fitting of the 227 two models and the two equations are discussed accordingly. 228

4.2 New approximation for etching time

Two different equations are proposed to calculate the etching time. In the first one, the etching time t_{e1} necessary to reveal 18 µm diameter of fission tracks is given in terms of the etchant concentrations as follows:

$$t_{e1} = \frac{G}{Cq}$$

235 (8)

Where q is a dimensionless adjusting parameter and G is a normalization etching time factor of dimension [min mol^qL^{-q}]. In the second one, the etching time t_{e2} is given as a function of NaOH molarity and ethanol fraction, x as follows:

$$t_{e2} = K \frac{a+x}{C^b}$$

240 (9)

Where x is the amount of ethanol volume, thus a and x are in L (litre) and C is the molar concentration $\frac{\text{mol}}{\text{L}}$ with $b \neq 1$, then K has the following unit $\left[\frac{\min}{L} \cdot \left(\frac{\text{mol}}{L}\right)^{b}\right]$. The physical meaning of the adjusting parameters could be deduced from their physical dimensions. However, due to their phenomenological nature, the physical meaning of the current parameters is not straightforward. At least a meaning could be deduced from their physical dimensions; such an attribution remains nevertheless hypothetically. K is thus simply a scaling time constant.

249 *4.3 New approximation for bulk etch*

The present work is suggesting two bulk etch rate equations. In the first one, bulk etch rate (V_{b1}) was treated as a bulk quantity without considering the added ethanol fraction, like literature ones. V_{b1} can be determined in terms of the etchant concentration, C as follows:

254
$$V_{b1} = Q e^{\left(\frac{C-i}{j}\right)^2}$$
 (10)

Where Q is the bulk etch rate normalization factor of dimension $\left[\frac{\mu m}{h}\right]$, while i and j are two adjusting parameters have concentration dimension, $\left[\frac{\text{mol}}{L}\right]$.

As stated before, no formula has been suggested by researchers to predict the bulk etch rate as a function of NaOH concentration, C and amount of ethanol volume, x in the etchant. Therefore, a second bulk etch rate formula, V_{b2} is suggested as a function of C and x simultaneously as follows:

261
$$V_{b2} = U \left(a_1 + x \right) exp \left(\frac{C - a_2}{a_3} \right)^2$$
(11)

Where U is a conversion adjusting factor of dimension $\left[\frac{\mu m}{h L}\right]$, x is amount of added ethanol in L, C is NaOH concentration. The free parameter a_1 has dimension of [L] while both of a_2 and a_3 have concentration dimension $\left[\frac{mol}{L}\right]$.

265

266 *4.4 New approximation for reciprocal bulk etch rate*

The reciprocal bulk etch rate using strong etching normalized to depth (by taking the whole removed layer as z=1) was obtained as follows:

269
$$\frac{1}{V_b(z)} = f + g e^{-z}$$
(12)

270 Where f and g are the reciprocal bulk etch rate factors of dimension of $\frac{h}{\mu m}$.

271

5. Results and Discussion

273 5.1 Etching time

Fig. 4 shows the variation of etching time with the different NaOH molarity for soft and strong etching, respectively. Tables 1 and 2 compile the adjusting parameters G and q of Eq. 8 and K, a and b of Eq. 9, respectively. From Fig. 4 and Table 1&2, one can observe that the suggested two equations produce the etching time with exactly same accuracy. However, Eq. 9 has the advantage of incorporating the ethanol volume, x.

280

281 *5.2 Bulk etch rate*

Experimental bulk etch rates for PADC SSNTD in the extended concentrations range of NaOH (2-22N) and added ethanol volumes of (0, 1, 2 and 3 mL) in 8 mL of NaOH aqueous solutions are illustrated in Fig. 5. Experimental uncertainty or error bars ($\approx 15\%$) is relatively high. It represents the standard deviation of the measured fission fragment diameters, D_{ff}. This higher uncertainty may be accepted in terms of the manual track diameter measurements, extended concentration range, highly active and strong etching process implemented.

Arrhenius-like model successfully reproduce the experimental data in the 289 extended molarity range, as shown in Fig. 5. The best fitting parameters are: 290 α =0.05, DF=10, and $\chi^2 < 18.307$. Table 3 compiles the fitting parameters of the 291 Arrhenius-like model. The degree of fitting is slightly degraded with increasing 292 amount of ethanol and NaOH concentration. Considering physical data of bulk 293 etch rates and Arrhenius fitting, the bulk etch kinetics can be explained chemically 294 based on collision theory. During etching process, etching species in the etching 295 solution collide with the molecules and atoms of the PADC detector with a range 296 of energies which is dependent on the etching temperature. Etching reaction would 297 take place if energies of colliding species are greater than activation energy of 298 etching (ϵ). The evaluated activation energies (ϵ) are given in Table 3. The mean 299 value 0.676 eV (with deviation ± 0.023 eV, i.e., <3.5%) remains in agreement with 300 previous resulted, reported in [15]. The activation energy of etching is weakly 301 dependent (or almost independent) on the amount of ethanol added to the solution. 302 This proves that etching process and chemical reaction rate within such extended 303 concentration range is still at equilibrium. 304

Fig. 6 illustrated the two multi-hit models (MHM-M8 & MHM-M15) 305 prediction to bulk etch rates of the extended concentration range incorporated with 306 the experimental data. Fitting parameters of multi-hit models are given in Table 4. 307 Inspecting Fig. 6 and Table 4 one can conclude that multi-hit model can reproduce 308 bulk etch rate with good accuracy. Activation energy, ε deduced by multi-hit 309 model is less than previously reported value ($\approx 0.70 \text{ eV}$) [2, 15, 19] however, still 310 have the same order of magnitude. Values of number of hits, v required for 311 activating the sensitive volume of the polymer were 2 for 0 ethanol and 1 in the 312 presence of ethanol as expected. This is one advantage for the multi-hit model 313 where this number of hits, v is another indicator about the etchant activity. As v 314 decreases (=1) for ethanol solution, as the etchant activity probably increases 315 compared to v=2 for soft etching. 316

Bulk etch rates can also be predicted using an equation with only two adjusting parameters [5]. This simple equation can reproduce the bulk etch rate with accuracy where the best fitting parameters are: α =0.05, DF=10, and χ^2 < 18.307 as given in Table 5 and illustrated in Fig. 7.

Experimental bulk etch rate and the non-linear fit using Eq. 10&11 for the limited (2-10N) and extended molarity are shown in Fig. 8 and 9, respectively. The new equations are predicting the bulk etch rate with the same high accuracy as

illustrated in Tables 6&7. The different adjusting parameters Q, i, j, U, a₁, a₂ and 324 a₃ of equations 10&11 are compiled. The adjusting parameters are showing slight 325 dependence on C and x. Of course, the 27 % ethanol content (3 mL) data shows 326 higher χ^2 value compared to the other ethanol volumes. However, it is statistically 327 accepted. This is expected in terms of bulk etch rate has been duplicated compared 328 to the closest ethanol volume of 20%. The best fitting parameters are: α =0.05, 329 DF=4, $\chi^2 < 9.488$ and α =0.05, DF=10, $\chi^2 < 18.307$ for the limited and extended 330 concentration ranges. By the goodness of the fitting curves in comparison with the 331 well-known models (Arrhenius and Multi hit) the validity of suggested empirical 332 formula has been determined. 333

In the previous paragraphs, the different equations for bulk etch rate were studied individually. All the equations were succeeded to reproduce the bulk etch rate as depicted in Fig. 10 but with different accuracy Tables 3-7. However, Eq. 11 is more advantageous since it adds both NaOH molarity and ethanol fraction as etching parameter. Eventually, this equation can be applied to other SSNTDs and chemical etchants, such as KOH.

Rigorous bulk etch rate V_b of PADC in NaOH/ethanol compared to NaOH/water and lowering etching time, t_e can be attributed to the fact that media containing methanol or ethanol has smaller dielectric constant. Attraction forces between electrical charges are enhanced in comparison to pure water. Therefore, it is likely that addition of alcohols in NaOH aqueous solution may partly lower the
relative static permittivity of the etchant and thus enhances hydroxide ion reactivity
on polar groups (carbonate ester groups).

347

348 *5.3 Reciprocal bulk etch rate*

PADC bulk and track etch rate variation with depth up to $\approx 80 \ \mu m$ was 349 intensively investigated where strong etching allows successive etching effectively 350 with reasonable etching time. The variation in V_{b} and V_{t} with depth for swift Si ion 351 are illustrated in Fig. 11. It was found that bulk etch rate is slightly increasing with 352 depth in agreement with Fujii and Nishimura, 1986 [35]. Simultaneously, the track 353 shaped etch-pits were measured for limited number of cones, and the 354 corresponding track etch rate Vt was determined. The track etch rate Vt is found to 355 be almost constant as expected for swift heavy ions passes through the bulk of 356 SSNTD. 357

³⁵⁸ Detector sensitivity, V for Si ion was determined and normalized to value ³⁵⁹ achieved at the first etched-off layer of a detector where $V = \frac{V_t}{V_b}$. Variation in ³⁶⁰ normalized sensitivity as a function of the removed layer h is presented in Fig. 12. ³⁶¹ One can observe that the detector sensitivity decreases with depth and reaches ³⁶² between 60-80% and becomes more stable at depth 25 µm inwards. This reduced

sensitivity with depth is due to the slight increase in V_b while V_t is almost constant. 363 The variation of V_b is an effect, probably specific for long etching time periods as 364 already mentioned in literature [35] (and references therein) in the case of a 2 365 GeV/nucleon iron nucleus track etched for more than 20 hours. The reasons for V_{b} 366 (and hence V) variation with depth may be due to a property of used plastic, 367 structural inhomogeneity in the detector material linked with its curing process 368 during fabrication and finally the successive etching process that follows heating 369 and drying of the detector sample many times. It was mentioned by Fujii and 370 Nishimura [35] that "most of the thick CR-39 sheets commercially available show 371 the depth dependence". However, this phenomenon deserves further investigation. 372

Experimental and calculated reciprocal bulk etch rate with normalized depth 373 (total depth, z=1) are illustrated in Fig. 13 where the best fitting of Eq. 12 was 374 obtained at f=0.04 and g=0.07. Prolonged etching with the amount of bulk-etch 375 exceeding 80 µm is necessary for producing swift heavy ions thick track membrane 376 [36] and study the track wall curvature development with removed layer through 377 the entire detector depth. Eq. 12 is fundamental for simulating the etched track 378 profiles and the shape of the track curvature developed with depth inside the 379 polymer and it can describe the reciprocal V_b as a function of (z) for soft etching 380 conditions as well. 381

383 6 Conclusions

Two empirical equations were proposed for bulk etch rate estimation. Both 384 equations were applied to soft and strong etching. A reasonable reproduction of 385 bulk etch rate was found at both limited and extended concentration range with 386 different ethanol volumes. Validity of suggested empirical formula has been 387 proved by goodness of the curves compared to Arrhenius and Multi-hits models. 388 Eq. 10 is using etchant concentration like literature equations. Eq. 11 has the 389 advantage that it reproduces the bulk etch rate as a function of both NaOH 390 concentration and ethanol fraction simultaneously. This equation can be extended 391 to other SSNTDs, and another etchant as well. 392

Two equations were suggested to calculate the etching time as a function of molarity and molarity with ethanol volume. The reduction in etching time can save considerable time in many applications.

Higher V_b and lower t_e of PADC can be explained by better solubility of etch product in ethanol than in water. Ethanol medium provides smaller dielectric constant and thus improves the attraction forces between electrical charges. Lower static permittivity of ethanol etchant enhances hydroxide reactivity on carbonate ester groups. Deep (up to 80 μ m) bulk etch rate and deep detector sensitivity were investigated. V_b shows slight increase while V show slight decrease with depth. Detector sensitivity is slightly decreasing with depth reaching 60-80 % after 25 μ m were removed. The SSNTD sensitivity may become quite stable at depth >25 μ m, so more accurate identification of swift heavy ion is possible with long etching plan.

Reciprocal bulk etch rate equation was given with the normalized depth. This equation is necessary for simulating etched track profiles. Deep-depth-effect is a subject of particular concern for producing thick nuclear track membranes and deep profile track curvature study.

In progress, etching time (t_e) for a given etching conditions will be estimated in terms of the Multi-hit model. Using geometric considerations, it is possible to estimate the frequency of collisions of ethanol molecules with the sensitive link of the detector molecules and obtain the release time of a given thickness in connection with the etching time.

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422 Acknowledgment

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- 429 **Figures Caption**
- 430 Fig. 1 Ester group hydrolysis in PADC CR-39 and the cleavage of ester431 linkage caused by hydroxide ion.
- 432 Fig. 2 Stages of the hydroxyl attack on the carbonyl during the etching433 process.

434 Fig. 3 The possible positions of the cleavage and the yielded etching outputs.

435 Fig. 4 Eqs. 8 and 9 prediction to the etching time necessary to obtain $D_{\rm ff} \approx 18$ 436 µm using different NaOH molarity for soft and strong etching,

- respectively. Eq. 9 has the advantage of incorporating the ethanolvolume, x.
- 439 Fig. 5 Arrhenius equation fit of bulk etch rate in extended NaOH/ethanol440 concentration range.
- 441 Fig. 6 Multi hit model of MHM-M8 and MHM-M15 fit of bulk etch rate in
 442 extended NaOH/ethanol concentration range.
- 443 Fig. 7 Al-Jubbori-2016 equation fit of bulk etch rate in extended
 444 NaOH/ethanol concentration range.
- 445 Fig. 8 Prediction of the newly suggested equations (Eq. 10 and Eq. 11) to
 446 bulk etch rate for the limited (2-10N) NaOH concentration range
 447 mixed with different ethanol volume.
- Fig. 9 Prediction of the newly suggested equations (Eq. 10 and Eq. 11) to
 bulk etch rate for the extended (2-22N) NaOH concentration range
 mixed with different ethanol volume.
- 451 Fig. 10 Experimental bulk etch rate and the corresponding calculated ones
 452 using Arrhenius, MHM-M8, Al-Jubbori-2016 and the new suggested
 453 Eq. 11 as a function of NaOH concentration and different ethanol
 454 volumes.

455	Fig. 11	The variation in the bulk and track etch rate with removed layer
456		(depth) for Si swift heavy ion.
457	Fig. 12	PADC sensitivity (V) normalized to value, achieved at the first
458		etched-off layer of a detector for Si swift heavy ion variation with
459		detector depth.
460	Fig. 13	Experimental and calculated reciprocal bulk etch rate with normalized
461		depth (total removed layer, z=1).
462		
463	Tables Cap	otion
464	Table 1	Fitting parameters for etch time formula (Eq. 8).
465	Table 2	Fitting parameters for etch time formula (Eq. 9).
466	Table 3	Arrhenius equation fitting parameters for the extended NaOH
466 467	Table 3	Arrhenius equation fitting parameters for the extended NaOH concentration and different ethanol volume at $B=1.25\times10^9$.
466 467 468	Table 3 Table 4	Arrhenius equation fitting parameters for the extended NaOH concentration and different ethanol volume at B=1.25×10 ⁹ . MHM-M8 and MHM-M15 fitting parameters for the extended NaOH
466 467 468 469	Table 3 Table 4	Arrhenius equation fitting parameters for the extended NaOH concentration and different ethanol volume at $B=1.25\times10^9$. MHM-M8 and MHM-M15 fitting parameters for the extended NaOH concentration and different ethanol volume at $B=1.25\times10^9$.
466 467 468 469 470	Table 3 Table 4 Table 5	Arrhenius equation fitting parameters for the extended NaOH concentration and different ethanol volume at $B=1.25\times10^9$. MHM-M8 and MHM-M15 fitting parameters for the extended NaOH concentration and different ethanol volume at $B=1.25\times10^9$. Al-Jubbori-2016 equation fitting parameters for the extended NaOH

472	Table 6	New equation (Eq. 10) fitting parameters for limited and extended
473		NaOH concentration range at different ethanol volume.
474	Table 7	New equation (Eq. 11) fitting parameters for limited and extended
475		NaOH concentration range at different ethanol volume.
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